

TO-263-2L Plastic-Encapsulate MOSFETS

IRFB640 MOSFET(N-Channel)

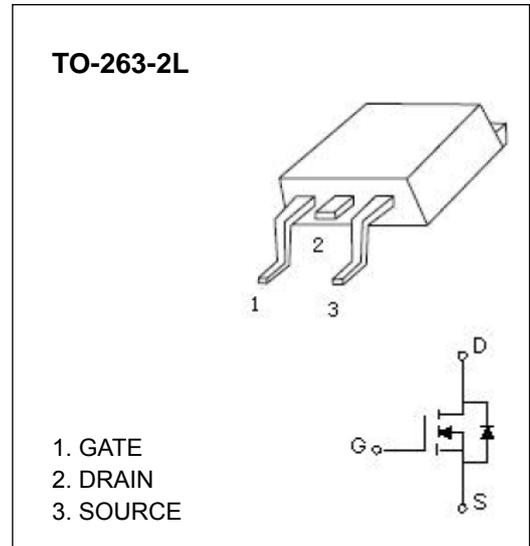
FEATURE

- Dynamic dv/dt Rating
- Repetitive Avalanche Rated
- Fast Switching
- Ease of Paralleling
- Simple Drive Requirement

DESCRIPTION

Third Generation HEXFETs from international Rectifier provide the designer with the best combination of fast switching , ruggedized device design, low on-resistance and cost effectiveness.

The TO-220-3L package is universally preferred for all commercial-industrial applications at power dissipation levels to approximately 50 watts. The low thermal resistance and low package cost of the TO-220-3L contribute to its wide acceptance throughout the industry.



MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------------|--|----------|-----------------------------|
| I_D | Continuous Drain Current, $V_{GS} @ 10\text{ V}$ | 18 | A |
| P_D | Power Dissipation | 2 | W |
| | Linear Derating Factor | 1.0 | W/ $^{\circ}\text{C}$ |
| V_{GS} | Gate-Source Voltage | ± 20 | V |
| E_{AS} | Single Pulse Avalanche Energy (note 1) | 580 | mJ |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient | 62.5 | $^{\circ}\text{C}/\text{W}$ |
| T_J | Junction Temperature | 150 | $^{\circ}\text{C}$ |
| T_{STG} | Storage Temperature | -55~+150 | $^{\circ}\text{C}$ |

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

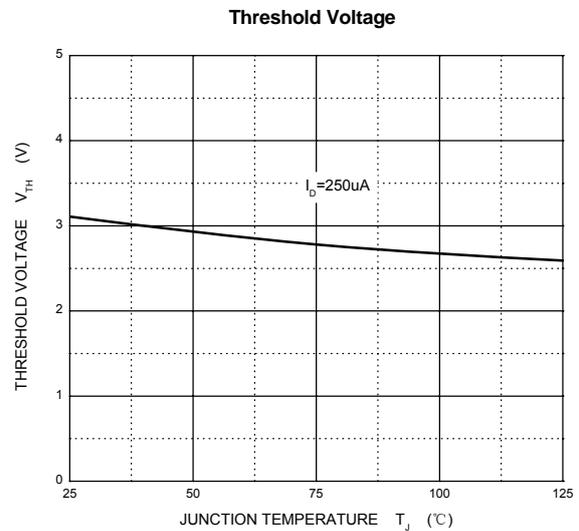
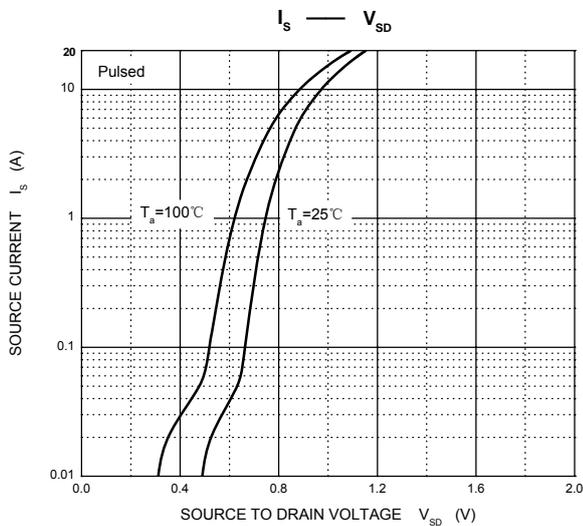
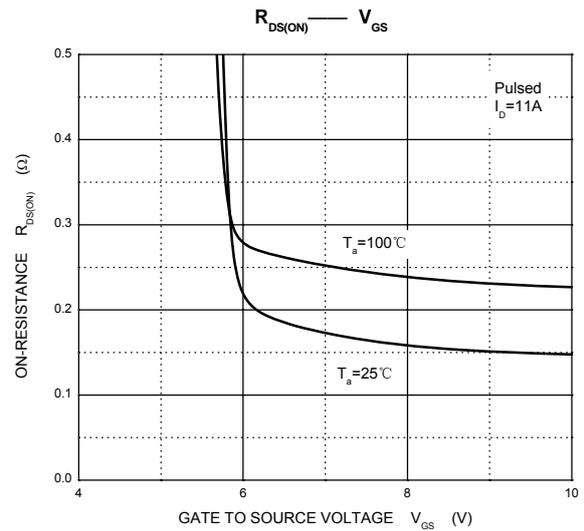
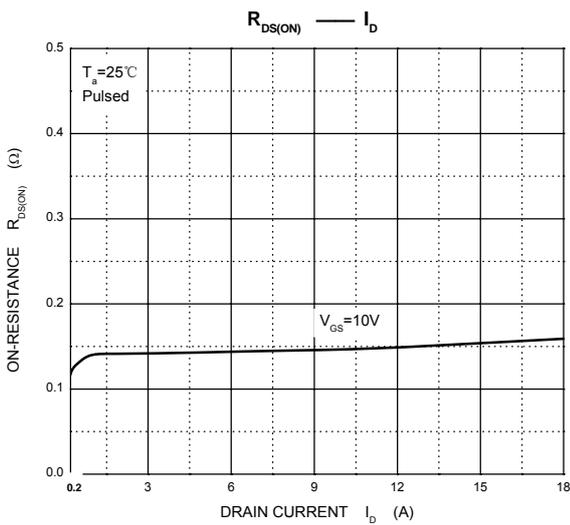
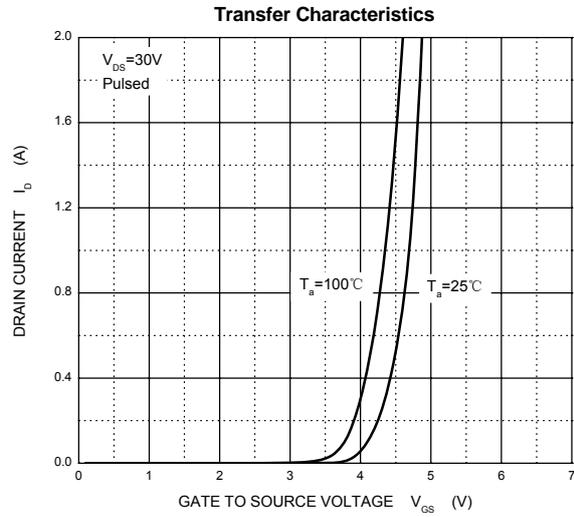
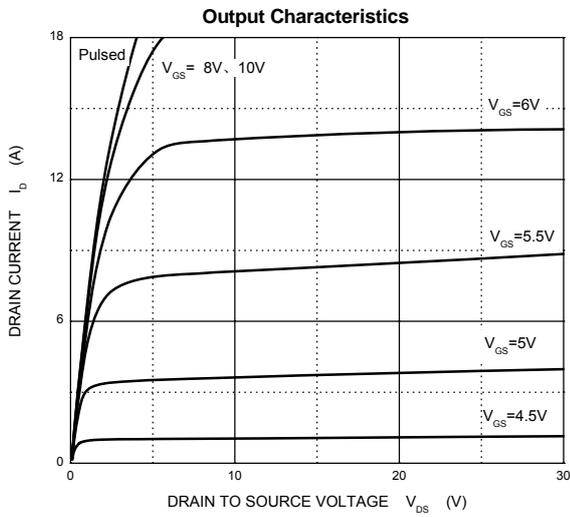
| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|---------------------------------------|----------------------|---|-----|------|------|------|
| Drain-source breakdown voltage | V _{(BR)DSS} | V _{GS} =0V, I _D =250μA | 200 | | | V |
| Gate-threshold voltage | V _{(GS)th} | V _{DS} =V _{GS} , I _D =250μA | 2 | | 4 | |
| Gate-body leakage | I _{GSS} | V _{DS} =0V, V _{GS} =±20V | | | ±100 | nA |
| Zero gate voltage drain current | I _{DSS} | V _{DS} =200V, V _{GS} =0V | | | 25 | μA |
| Drain-source on-resistance (note 2) | R _{DS(on)} | V _{GS} =10V, I _D =11A | | | 0.18 | Ω |
| Forward transconductance (note 2) | g _{fs} | V _{DS} =50V, I _D =11A | 6.7 | | | S |
| Diode forward voltage (note 2) | V _{SD} | I _S =18A, V _{GS} =0V | | | 2 | V |
| Input capacitance (note 3) | C _{iss} | V _{DS} =25V, V _{GS} =0V, f=1MHz | | 1300 | | pF |
| Output capacitance (note 3) | C _{oss} | | | 430 | | |
| Reverse transfer capacitance (note 3) | C _{rss} | | | 130 | | |
| Turn-on time(note 2,3) | t _{d(on)} | V _{DD} =100V, R _D =5.4Ω, I _D =18A, R _G =9.1Ω | | 14 | | ns |
| Rise time | t _r | | | 51 | | |
| Turn-off time (note 2,3) | t _{d(off)} | | | 45 | | |
| Fall time (note 2,3) | t _f | | | 36 | | |

Notes:

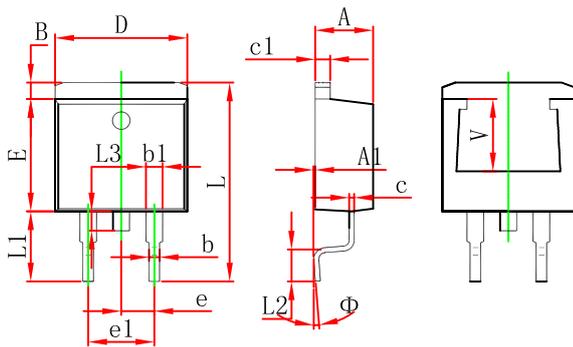
1. V_{DD}=50V, starting T_J=25°C, L=2.7mH, R_G=25Ω, I_{AS}=18A.
2. Pulse test: Pulse width≤300μs, duty cycle≤2%.
3. These parameters have no way to verify.

Typical Characteristics

IRFB640

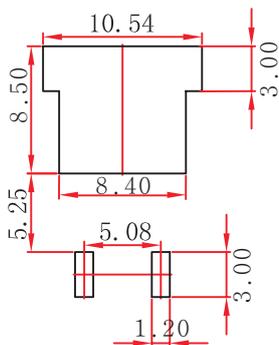


TO-263-2L Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.470 | 4.670 | 0.176 | 0.184 |
| A1 | 0.000 | 0.150 | 0.000 | 0.006 |
| B | 1.120 | 1.420 | 0.044 | 0.056 |
| b | 0.710 | 0.910 | 0.028 | 0.036 |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 |
| c | 0.310 | 0.530 | 0.012 | 0.021 |
| c1 | 1.170 | 1.370 | 0.046 | 0.054 |
| D | 10.010 | 10.310 | 0.394 | 0.406 |
| E | 8.500 | 8.900 | 0.335 | 0.350 |
| e | 2.540 TYP. | | 0.100 TYP. | |
| e1 | 4.980 | 5.180 | 0.196 | 0.204 |
| L | 14.940 | 15.500 | 0.588 | 0.610 |
| L1 | 4.950 | 5.450 | 0.195 | 0.215 |
| L2 | 2.340 | 2.740 | 0.092 | 0.108 |
| L3 | 1.300 | 1.700 | 0.051 | 0.067 |
| Φ | 0° | | 8° | |
| V | 5.600 REF. | | 0.220 REF. | |

TO-263-2L Suggested Pad Layout



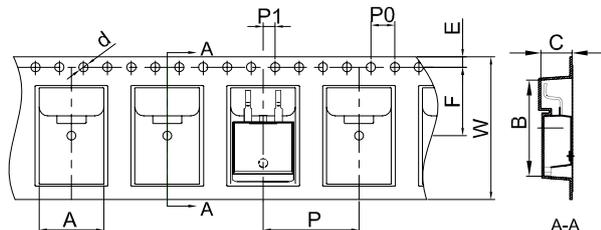
- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

TO-263-2L Tape and Reel

TO-263-2L Embossed Carrier Tape

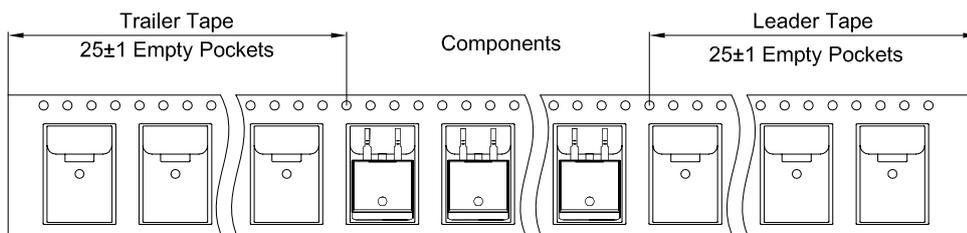


Packaging Description:

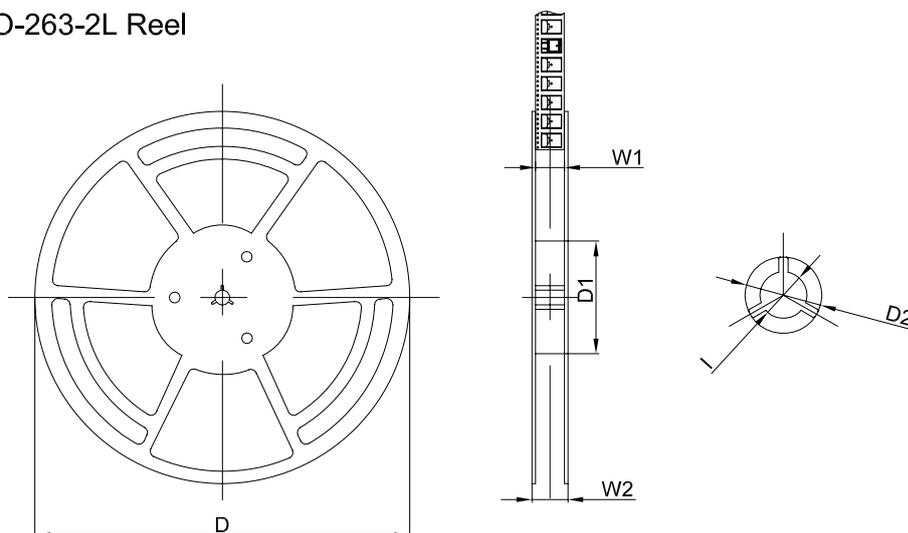
TO-263-2L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 800 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|-----------|
| Pkg type | A | B | C | d | E | F | P0 | P | P1 | W |
| TO-263-2L | 10.80 | 16.13 | 5.21 | Ø1.55 | 1.75 | 11.50 | 4.00 | 16.00 | 2.00 | 24.00 |
| (Tolerance) | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +0.3/-0.1 |

TO-263-2L Tape Leader and Trailer



TO-263-2L Reel



| Dimensions are in millimeter | | | | | | |
|------------------------------|---------|--------|--------|------|------|--------|
| Reel Option | D | D1 | D2 | W1 | W2 | I |
| 13" Dia | Ø330.00 | 100.00 | Ø21.00 | 24.4 | 30.4 | Ø13.00 |
| Tolerance | +/-2 | +/-1 | +/-1 | +/-1 | +/-1 | +/-1 |

| REEL | Reel Size | Box | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|---------|-----------|---------|--------------|-----------|-----------------|----------|
| 800 pcs | 13 inch | 800 pcs | 340×336×36 | 8,000 pcs | 400×353×365 | |